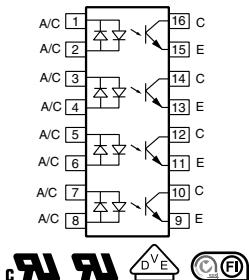
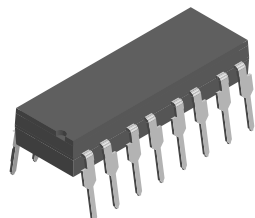


Optocoupler, Phototransistor Output, AC Input (Quad Channel)


RoHS
COMPLIANT

LINKS TO ADDITIONAL RESOURCES


SPICE
Models

DESCRIPTION

The TCET4600 consists of a phototransistor optically coupled to 2 gallium arsenide infrared-emitting diodes in 16 pin lead plastic dual inline package.

FEATURES

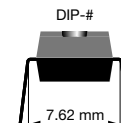
- Extra low coupling capacity - typical 0.2 pF
- High common mode rejection
- Low temperature coefficient of CTR
- Rated impulse voltage (transient overvoltage) $V_{IOTM} = 10 \text{ kV peak}$
- Isolation test voltage (partial discharge test voltage) $V_{pd} = 1.6 \text{ kV peak}$
- Rated isolation voltage (RMS includes DC) $V_{IOWM} = 600 V_{RMS}$
- Rated recurring peak voltage (repetitive) $V_{IORM} = 890 V_{peak}$
- Thickness though insulation $\geq 0.4 \text{ mm}$
- Creepage current resistance according to VDE 0303 / IEC 60112 comparative tracking index: CTI ≥ 175
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AGENCY APPROVALS

- [UL](#) / [cUL](#) 1577
- [DIN EN 60747-5-5 \(VDE 0884\)](#)
- [FIMKO](#)

ORDERING INFORMATION

T	C	E	T	4	6	0	0
PART NUMBER							



AGENCY CERTIFIED / PACKAGE	CTR (%)
	$\pm 5 \text{ mA}$
UL, cUL, VDE, FIMKO	20 to 300
DIP-16, quad channel	TCET4600



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
Forward current		I_F	± 60	mA
Forward surge current	$t_p \leq 10\text{ }\mu\text{s}$	I_{FSM}	± 1.5	A
Power dissipation		P_{diss}	100	mW
Junction temperature		T_j	125	$^{\circ}\text{C}$
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5$, $t_p \leq 10\text{ ms}$	I_{CM}	100	mA
Power dissipation		P_{diss}	150	mW
Junction temperature		T_j	125	$^{\circ}\text{C}$
COUPLER				
Total power dissipation		P_{tot}	250	mW
Operating ambient temperature range		T_{amb}	-55 to +100	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	-55 to +150	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	2 mm from case, $t \leq 10\text{ s}$	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability

⁽¹⁾ Refer to wave profile for soldering conditions for through hole devices

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = \pm 50\text{ mA}$	V_F	-	1.25	1.6	V
Junction capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_j	-	50	-	pF
OUTPUT						
Collector emitter voltage	$I_C = 100\text{ }\mu\text{A}$	V_{CEO}	70	-	-	V
Emitter collector voltage	$I_E = 100\text{ }\mu\text{A}$	V_{ECO}	7	-	-	V
Collector dark current	$V_{CE} = 20\text{ V}$, $I_F = 0\text{ A}$, $E = 0$	I_{CEO}	-	-	100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 10\text{ mA}$, $I_C = 1\text{ mA}$	V_{CEsat}	-	-	0.3	V
Cut-off frequency	$V_{CE} = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	f_c	-	100	-	kHz
Coupling capacitance	$f = 1\text{ MHz}$	C_k	-	0.3	-	pF

Note

- Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements

CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$V_{CE} = 5\text{ V}$, $I_F = \pm 5\text{ mA}$	CTR	20	-	300	%

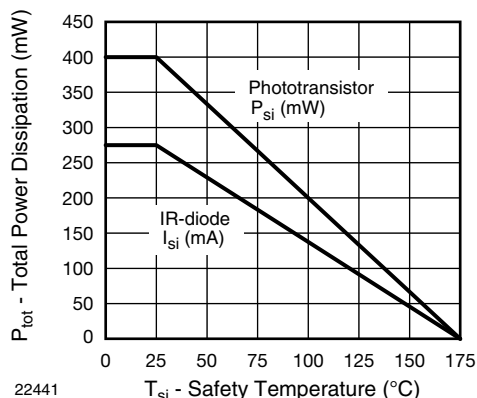


Fig. 1 - Derating Diagram

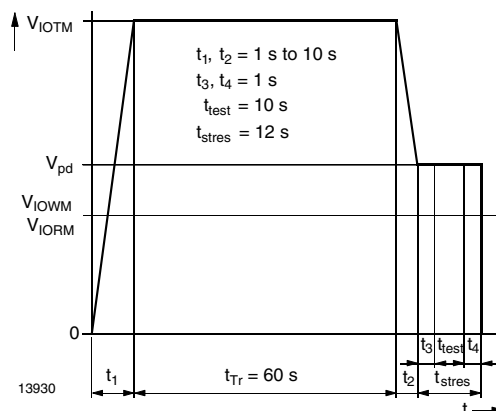


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\ \Omega$, (see Fig. 3)	t_d	-	3	-	μs
Rise time	$V_S = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\ \Omega$, (see Fig. 3)	t_r	-	3	-	μs
Fall time	$V_S = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\ \Omega$, (see Fig. 3)	t_f	-	4.7	-	μs
Storage time	$V_S = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\ \Omega$, (see Fig. 3)	t_s	-	0.3	-	μs
Turn-on time	$V_S = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\ \Omega$, (see Fig. 3)	t_{on}	-	6	-	μs
Turn-off time	$V_S = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\ \Omega$, (see Fig. 3)	t_{off}	-	5	-	μs
Turn-on time	$V_S = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 1\text{ k}\Omega$, (see Fig. 4)	t_{on}	-	9	-	μs
Turn-off time	$V_S = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 1\text{ k}\Omega$, (see Fig. 4)	t_{off}	-	10	-	μs

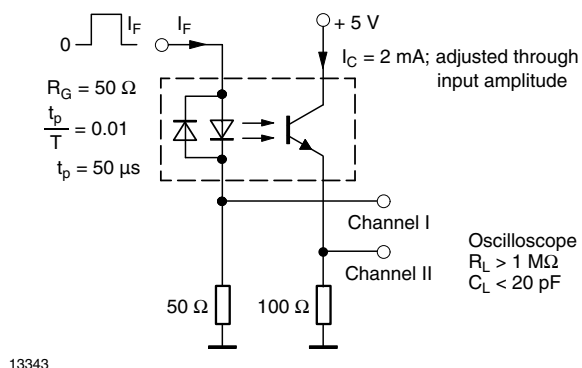


Fig. 3 - Test Circuit, Non-Saturated Operation

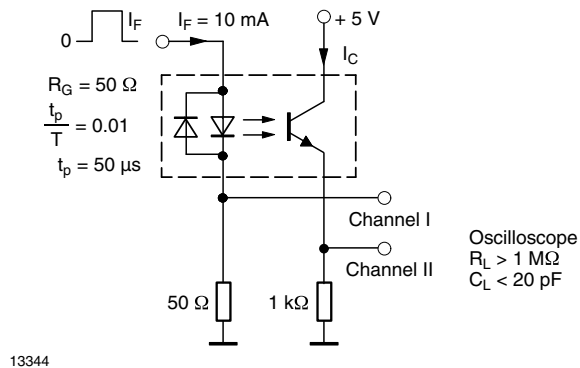


Fig. 4 - Test Circuit, Saturated Operation

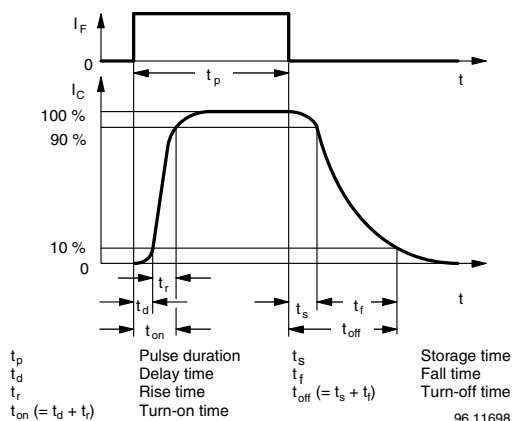


Fig. 5 - Switching Times

SAFETY AND INSULATION RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	$t = 1 \text{ min}$	V_{ISO}	4420	V_{RMS}
Maximum transient isolation voltage		V_{IOTM}	10 000	V_{peak}
Maximum repetitive peak isolation voltage		V_{IORM}	890	V_{peak}
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 \text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500 \text{ V}, T_{amb} = 100 \text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
	$V_{IO} = 500 \text{ V}, T_{amb} = 150 \text{ }^{\circ}\text{C}$ (construction test only)	R_{IO}	$\geq 10^9$	Ω
Output safety power		P_{SO}	400	mW
Input safety current		I_{SI}	275	mA
Safety temperature		T_S	175	$^{\circ}\text{C}$
Creepage distance	Standard DIP-16		≥ 7	mm
Clearance distance	Standard DIP-16		≥ 7	mm
Creepage distance	400 mil DIP-16		≥ 8	mm
Clearance distance	400 mil DIP-16		≥ 8	mm
Insulation thickness		DTI	≥ 0.4	mm
Partial discharge test voltage - routine test	100 %, $t_{test} = 1 \text{ s}$	V_{pd}	1.669	kV _{peak}
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s}$, (see Fig. 2)	V_{pd}	1.424	kV _{peak}

Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits

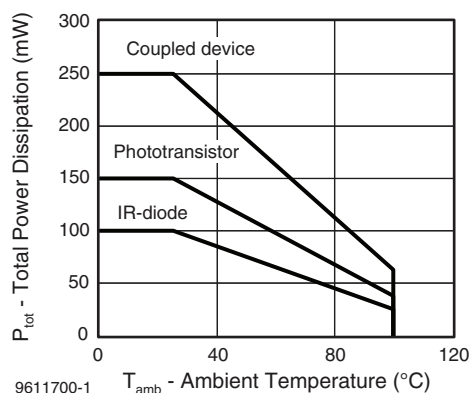
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

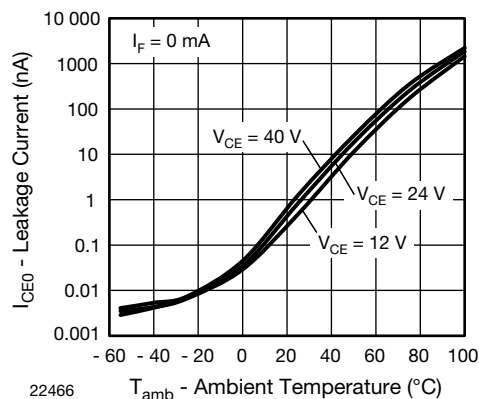


Fig. 9 - Leakage Current vs. Ambient Temperature

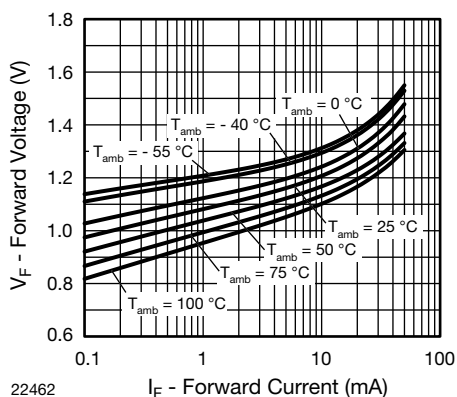


Fig. 7 - Forward Current vs. Forward Voltage

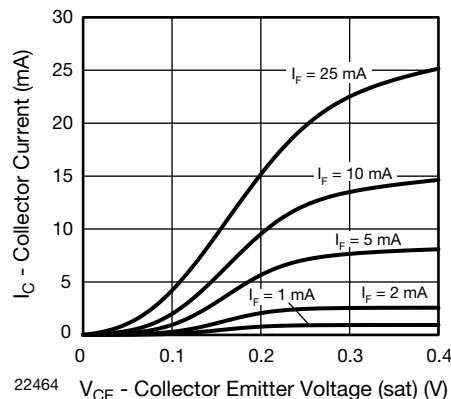


Fig. 10 - Collector Current vs. Collector Emitter Voltage (saturated)

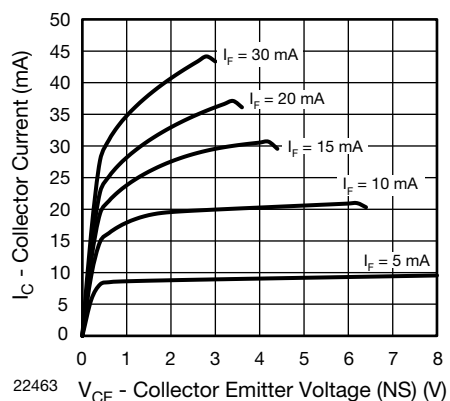


Fig. 8 - Collector Current vs. Collector Emitter Voltage (non-saturated)

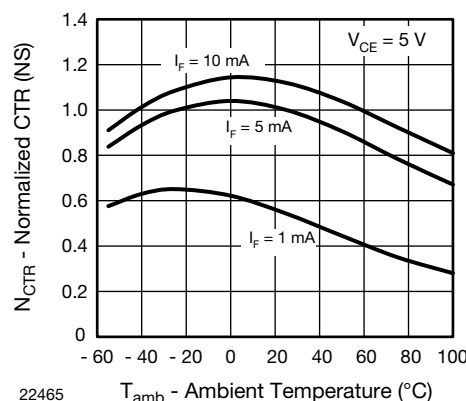


Fig. 11 - Normalized CTR (non-saturated) vs. Ambient Temperature

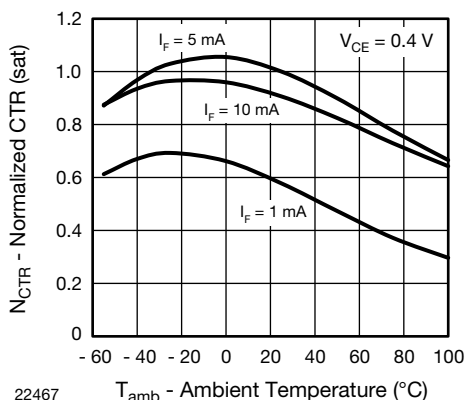


Fig. 12 - Normalized CTR (saturated) vs. Ambient Temperature

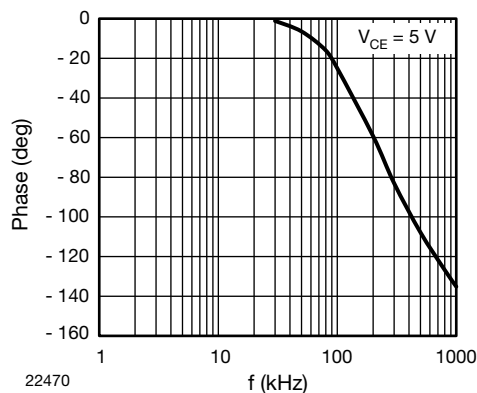
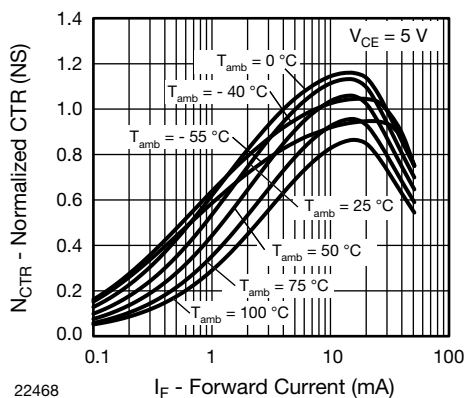

Fig. 15 - F_{CTR} vs. Phase Angle


Fig. 13 - Normalized CTR (non-saturated) vs. Forward Current

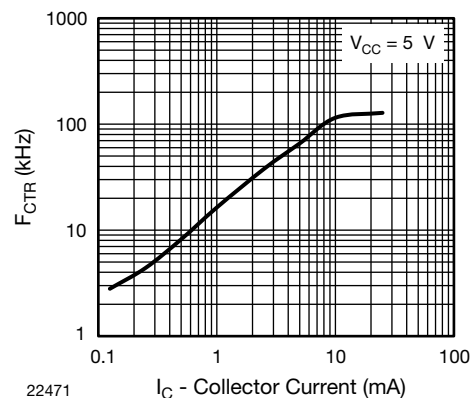
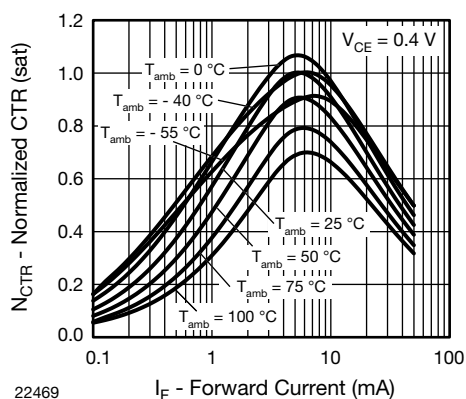

Fig. 16 - F_{CTR} vs. I_C


Fig. 14 - Normalized CTR (saturated) vs. Forward Current

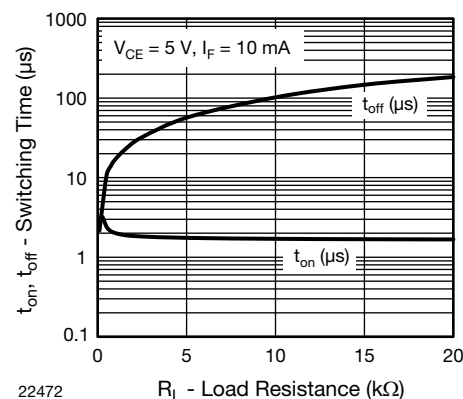
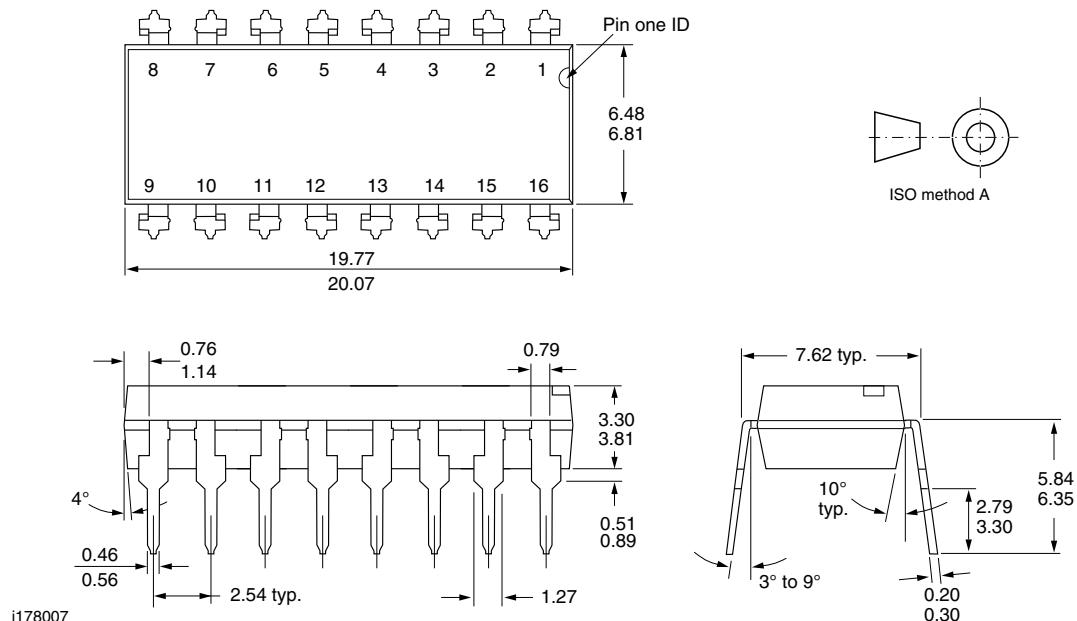


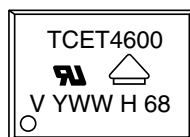
Fig. 17 - Switching Time vs. Load Resistance



PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example)





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